ETE706 - Materials for nanostructures, electronics devices and micromachines

COURSE OUTLINE

(1) GENERAL

SCHOOL	SCHOOL OF ENGINEERING				
ACADEMIC UNIT	DEPARTMENT OF MATERIALS SCIENCE AND				
	ENGINEERING				
LEVEL OF STUDIES	UNDERGRADUATE				
COURSE CODE	ETE706 SEMESTER 7				
COURSE TITLE	Materials for nanostructures, electronics devices and micromachines				
INDEPENDENT TEACHING ACTIVITIES if credits are awarded for separate components of the course, e.g. lectures, laboratory exercises, etc. If the credits are awarded for the whole of the course, give the weekly teaching hours and the total credits			WEEKLY TEACHING HOURS	5	CREDITS
Leo	ctures and rec	itation	3		3
Add rows if necessary. The organization of teaching and the teaching methods used are described in detail at (d).					
COURSE TYPE general background, special background, specialized general knowledge, skills development	specialized general knowledge				
PREREQUISITE COURSES:	Quantum theory of matter Atomic and electronic structure of matter				
LANGUAGE OF INSTRUCTION and EXAMINATIONS:	GREEK				
IS THE COURSE OFFERED TO ERASMUS STUDENTS					
COURSE WEBSITE (URL)					

(2) LEARNING OUTCOMES

Learning outcomes

The course learning outcomes, specific knowledge, skills and competences of an appropriate level, which the students will acquire with the successful completion of the course are described.

Consult Appendix A

- Description of the level of learning outcomes for each qualifications cycle, according to the Qualifications Framework of the European Higher Education Area
- Descriptors for Levels 6, 7 & 8 of the European Qualifications Framework for Lifelong Learning and Appendix B
- Guidelines for writing Learning Outcomes

Knowledge: Students are taught the properties of modern materials used in the manufacturing of the most important electronic devices such as high-frequency transistors, light emitting diodes and high-efficiency solar cells. Understanding of their operating principles

Skills: Calculation of characteristic sizes related to the operation and performance of electronic devices. Recognition, handling and design of different types of materials heterojunctions (types I, II and III).

Competences: Recognition of the operating characteristics of advanced devices such as photodiodes, infrared sensors and biosensors. Comparative analysis of operation and architecture, general design.

General Competences

Taking into consideration the general competences that the degree-holder must acquire (as these appear in the Diploma Supplement and appear below), at which of the following does the course aim? Search for, analysis and synthesis of data and information, Project planning and management Respect for difference and multiculturalism with the use of the necessary technology Adapting to new situations Respect for the natural environment Decision-making Showing social, professional and ethical responsibility Working independently and sensitivity to gender issues Team work Criticism and self-criticism Production of free, creative and inductive thinking Working in an international environment Working in an interdisciplinary environment Production of new research ideas Others ...

Autonomous work

• Production of new research ideas

• Promoting free, creative and inductive thinking

(3) SYLLABUS

Heterostructures of semiconductor materials type I, II and III. Semiconductor materials III-V for the manufacturing of modern electronic devices. Emission of light and infrared detectors. Exercises. Lasers of quantum potential wells. Lasers of quantum dots. Crystalline silicon solar cells. High Frequency Transistors. Infrared Sensors and Light Diodes. Molecular diodes. Microelectronic systems. Biosensors.

(4) TEACHING and LEARNING METHODS - EVALUATION

DELIVERY Face-to-face, Distance learning, etc.	In class, lectures			
USE OF INFORMATION AND COMMUNICATIONS TECHNOLOGY Use of ICT in teaching, laboratory education, communication with students				
TEACHING METHODS	Activity	Semester workload		
The manner and methods of teaching are described in detail. Lectures, seminars, laboratory practice,	Lectures	39		
fieldwork, study and analysis of bibliography, tutorials, placements, clinical practice, art workshop, interactive teaching,	Self-study for preparing for final examination	36		
educational visits, project, essay writing, artistic creativity, etc. The student's study hours for each learning activity are given as well as the hours of non-				
directed study according to the principles of the ECTS				
	Course total	75		
STUDENT PERFORMANCE EVALUATION				
Description of the evaluation procedure Language of evaluation, methods of	LANGUAGE OF EVALUATION: Greek			
evaluation, summative or conclusive, multiple choice questionnaires, short- answer questions, open-ended questions, problem solving, written work,	METHOD OF EVALUATION:			
essay/report, oral examination, public presentation, laboratory work, clinical examination of patient, art interpretation, other	Written final exam: • Development and explanation of theory • Developing and resolving problems			
other Specifically-defined evaluation criteria are given, and if and where they are accessible	• Developing and resolving problems			

to students.	

(5) ATTACHED BIBLIOGRAPHY

- Suggested bibliography:

- Quantum Wells, Wires and Dots , Theoretical and Computational Physics , Paul Harrison , John Wiley and Sons ,ISBN 0-471-98495-7
- Principles of nanoelectronics , George W. Hanson, Translated in Greek: Nikolaos Kofidis , 2009 TZIOLA Publications , ISBN 978-960-418-165-0